

0.1 GHz to 6 GHz Silicon SP5T Switch

Data Sheet

ADRF5250

FEATURES

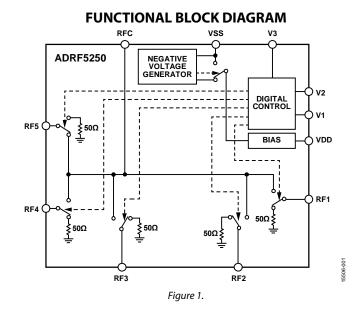
Nonreflective 50 Ω design Low insertion loss: 1.5 dB at 4 GHz High isolation: 50 dB at 4 GHz High input linearity 0.1 dB compression (P0.1dB): 34 dBm typical Third-order intercept (IP3): 57 dBm typical High power handling at 85°C 33 dBm through path 27 dBm terminated path ESD rating 3.5 kV HBM, Class 2 Single-supply or dual-supply operation Optional internal negative voltage generator (NVG) 1.8 V logic-compatible control 4 mm × 4 mm, 24-lead LFCSP

APPLICATIONS

Cellular/4G infrastructure Wireless infrastructure Mobile radios Test equipment

GENERAL DESCRIPTION

The ADRF5250 is a general-purpose, single-pole, five-throw (SP5T), nonreflective switch manufactured using a silicon process. The ADRF5250 is available in a 4 mm \times 4 mm, 24-lead lead frame chip scale package (LFCSP) and provides high isolation and low insertion loss from 100 MHz to 6 GHz.



The ADRF5250 incorporates a negative voltage generator to operate with a single positive supply voltage from 3.3 V to 5 V applied to the VDD pin when the VSS pin is connected to ground. The negative voltage generator can be disabled when an external negative supply voltage of -3.3 V is applied to the VSS pin. The ADRF5250 provides a 1.8 V logic-compatible, 3-pin control interface.

Rev. 0

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REVISION HISTORY

6/2017—Revision 0: Initial Version

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SPECIFICATIONS

 V_{DD} = 5 V, V_{SS} = 0 V, V_1 = V_2 = V_3 = 0 V/V_{DD}, T_{CASE} = 25°C, 50 Ω system, unless otherwise noted.

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
FREQUENCY RANGE	f		0.1		6	GHz
INSERTION LOSS						
Between RFC and RFx (On)		0.1 GHz to 2 GHz		1.3		dB
		2 GHz to 4 GHz		1.5		dB
		4 GHz to 6 GHz		1.8		dB
ISOLATION						
Between RFC and RFx (Off)		0.1 GHz to 2 GHz		55		dB
		2 GHz to 4 GHz		50		dB
		4 GHz to 6 GHz		46		dB
RETURN LOSS						
RFC and RFx (On)		0.1 GHz to 2 GHz		15		dB
		2 GHz to 4 GHz		13		dB
		4 GHz to 6 GHz		13		dB
RFx (Off)		0.1 GHz to 2 GHz		17		dB
		2 GHz to 4 GHz		15		dB
		4 GHz to 6 GHz		8		dB
SWITCHING						
Rise Time	trise	10% to 90% of radio frequency (RF) output		40		ns
Fall Time	t _{FALL}	10% to 90% of RF output		80		ns
On and Off Time	ton, toff	50% of digital control voltage (V1, V2, V3) to 90% of RF output	of 150		ns	
Settling Time (RFx to RFx)						
0.1 dB		50% of V_1 , V_2 , V_3 to 0.1 dB of final RF output	400		ns	
0.05 dB		50% of V_1 , V_2 , V_3 to 0.05 dB of final RF output	500		ns	
INPUT LINEARITY						
0.1 dB Compression	P0.1dB	34			dB	
Third-Order Intercept	IP3	57			dBm	
SUPPLY CURRENT		VDD, VSS pins				
Positive	I _{DD}	NVG enabled ($V_{ss} = 0 V$)		360		μΑ
		NVG disabled ($V_{ss} = -3.3 V$)		280		μΑ
Negative	lss	NVG disabled ($V_{SS} = -3.3 V$)	-60		μΑ	
DIGITAL CONTROL INPUTS		V1, V2, V3 pins				
Voltage						
Low	VINL	V _{DD} = 3.3 V	0		0.8	V
		$V_{DD} = 5 V$	0		1.2	V
High V _{INH}		V _{DD} = 3.3 V	1.3		3.3	V
		$V_{DD} = 5 V$	1.6		5	V
Current						
Low and High	I _{INL} , I _{INH}	$V_{DD} = 3.3 \text{ V to } 5 \text{ V}$		<1		μΑ

ADRF5250

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Мах	Unit
RECOMMENDED OPERATING CONDITIONS						
Supply Voltage						
Positive	V _{DD}		3.0		5.25	V
Negative	Vss		-3.45		-3.15	V
Digital Control Voltage	V ₁ , V ₂ , V ₃		0		VDD	V
Maximum RF Input Power ¹	PIN					
T _{CASE} = 105°C		Through path ($V_{DD} = 3.3 \text{ V to } 5 \text{ V}$)			30	dBm
		Terminated path			24	dBm
		Hot switching			24	dBm
$T_{CASE} = 85^{\circ}C$		Through path ($V_{DD} = 3.3 \text{ V to } 5 \text{ V}$)			33	dBm
		Terminated path			27	dBm
		Hot switching			27	dBm
Case Temperature	TCASE		-40		+105	°C

¹ Exposure to levels between the recommended operating conditions and the absolute maximum rating conditions for extended period may affect device reliability.

ABSOLUTE MAXIMUM RATINGS

For recommended operating conditions, see Table 1.

Table 2.

Parameter	Rating
Positive Supply Voltage (V _{DD})	-0.3 V to +5.5 V
Negative Supply Voltage (Vss)	-3.6 V to +0.3 V
Digital Control Input Voltage (V1, V2, V3)	-0.3 V to V _{DD} + 0.5 V
RF Input Power	
Through Path	35 dBm
Terminated Path	34 dBm
All Off State, RFC as Input	24 dBm
Hot Switching	
RFC as Input	
RFx to RFx	32 dBm
All Off to RFx	24 dBm
RFx as Input	
RFx to RFx	34 dBm
All Off to RFx	34 dBm
Temperature	
Junction, T _J	135°C
Storage	–65°C to +150°C
Reflow (MSL3 Rating)	260°C
Junction to Case Thermal Resistance, θ_{JC}	
Through Path	90°C/W
Terminated Path	100°C/W
ESD Sensitivity	
Human Body Model (HBM)	3.5 kV (Class 2)
Field Induced Device Model (FICDM)	1.25 kV (Class IV)

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating can be applied at any one time.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

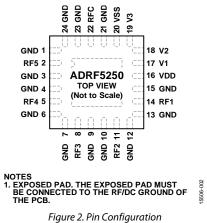


Table 3. Pin Function Descriptions

	Table 5. Fill Function Descriptions					
Pin No.	Mnemonic	Description				
1, 3, 4, 6, 7, 9, 10, 12, 13, 15, 21, 23, 24	GND	Ground. These pins must be connected to the RF/dc ground of the printed circuit board (PCB).				
2	RF5	RF Throw Port 5. This pin is dc coupled and no dc blocking capacitor is necessary when the RF line potential is within 0 V dc.				
5	RF4	RF Throw Port 4. This pin is dc coupled and no dc blocking capacitor is necessary when the RF line potential is within 0 V dc.				
8	RF3	RF Throw Port 3. This pin is dc coupled and no dc blocking capacitor is necessary when the RF line potential is within 0 V dc.				
11	RF2	RF Throw Port 2. This pin is dc coupled and no dc blocking capacitor is necessary when the RF line potential is within 0 V dc.				
14	RF1	RF Throw Port 1. This pin is dc coupled and no dc blocking capacitor is necessary when the RF line potential is within 0 V dc.				
16	VDD	Positive Supply Voltage.				
17	V1	Digital Input Voltage Applied to the Least Significant Bit (LSB) of Digital Interface for Controlling RF Path State. See Table 5.				
18	V2	Digital Input Voltage Applied to the Second Bit of Digital Interface for Controlling RF Path State. See Table 5.				
19	V3	Digital Input Voltage Applied to the Most Significant Bit (MSB) of Digital Interface for Controlling RF Path State. See Table 5.				
20	VSS	Optional Negative Supply Voltage. This pin can be connected to ground to operate with the internal negative voltage generator. The internal negative voltage generator is disabled when this pin is connected to an external 3.3 V supply.				
22	RFC	RF Common Port. This pin is dc-coupled and no dc blocking capacitor is necessary when the RF line potential is within 0 V dc.				
	EPAD	Exposed Pad. The exposed pad must be connected to the RF/dc ground of the PCB.				

INTERFACE SCHEMATICS

Figure 3. RF Pin Interface Schematic

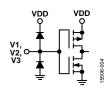


Figure 4. Digital Pin Interface Schematic

TYPICAL PERFORMANCE CHARACTERICS

INSERTION LOSS, RETURN LOSS, AND ISOLATION

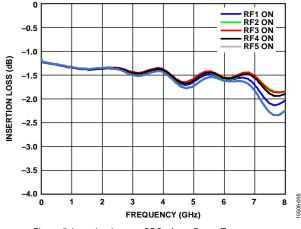
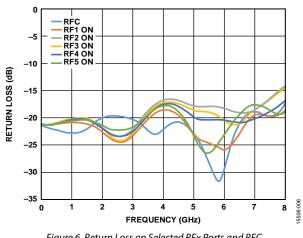
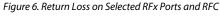


Figure 5. Insertion Loss on RF Paths at Room Temperature





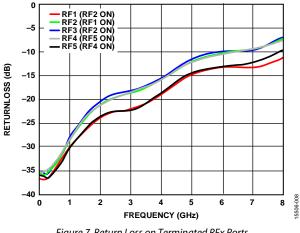
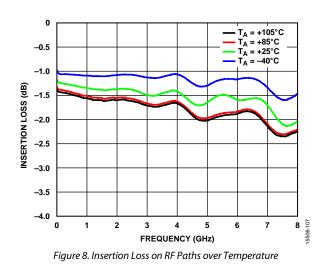


Figure 7. Return Loss on Terminated RFx Ports



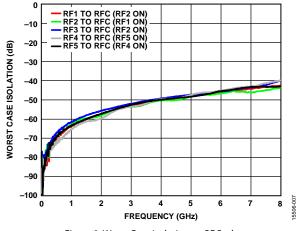


Figure 9. Worst Case Isolation on RF Paths

INPUT POWER COMPRESSION AND THIRD-ORDER INTERCEPT (IP3)

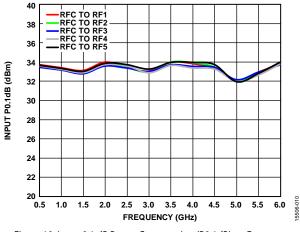


Figure 10. Input 0.1 dB Power Compression (P0.1dB) vs. Frequency, $V_{DD} = 3.3 V$, $V_{SS} = 0 V$

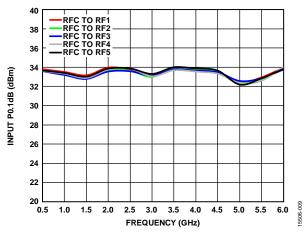


Figure 11. Input 0.1 dB Power Compression (P0.1dB) vs. Frequency, $V_{DD} = 5 V, V_{SS} = 0 V$

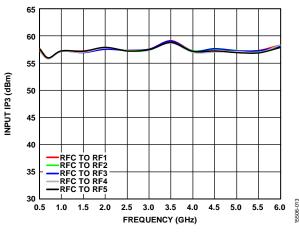


Figure 12. Input IP3 vs. Frequency, $V_{DD} = 5 V$, $V_{SS} = 0 V$

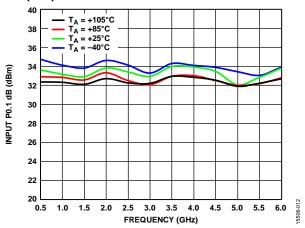


Figure 13. Input 0.1 dB Power Compression vs. Frequency over Temperature, $V_{DD} = 3.3 V$, $V_{SS} = 0 V$

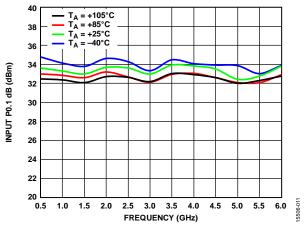
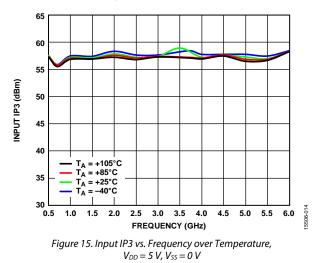
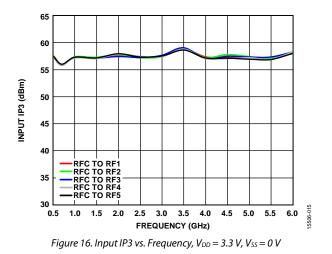
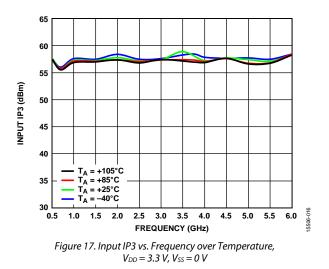


Figure 14. Input 0.1 dB Power Compression (P0.1dB) vs. Frequency over Temperature, $V_{DD} = 5 V$, $V_{SS} = 0 V$



ADRF5250





THEORY OF OPERATION

The ADRF5250 requires a positive supply voltage applied to the VDD pin and 0 V or -3.3 V supply voltage applied to the VSS pin. Bypass capacitors are recommended on the supply and digital control lines to minimize RF coupling. An incorporated negative supply generator is enabled or disabled depending on the applied V_{SS} supply voltage. Table 4 describes the operation mode of that negative supply generator.

Table 4. Negative Voltage Generator Operation Mode					
V _{ss} Test Conditions/Comments					
0 V	The incorporated negative voltage generator is				

0 V	The incorporated negative voltage generator is enabled
–3.3 V	The incorporated negative voltage generator is disabled

The ADRF5250 is internally matched to 50 Ω at the RF common port (RFC) and the RF throw ports (RF1 to RF5); therefore, no external matching components are required. All of the RF ports are dc-coupled to 0 V, and no dc blocking is required at the RF ports when the RF line potential is equal to 0 V. The design is bidirectional; the RF input signal can be applied to the RFC port while the RF throw port (RF1 to RF5) is output, or vice versa.

The ADRF5250 has a 3-bit, 1.8 V logic-compatible control interface that is controlled through the V1, V2, and V3 digital control voltage pins. A small bypassing capacitor is recommended on these digital signal lines to improve the RF signal isolation. The V1 and V3 test points correspond to the LSB and MSB of the digital control interface of the ADRF5250. The modes of the RF paths are determined as shown in Table 5. When an RF path is on, the RF signal is conducted equally well in both directions between its throw port (RFx) and common port (RFC). Otherwise, each RFx path is terminated to an internal 50 Ω resistor that provides high loss between the insertion loss path and its throw ports.

Table 5.	Control	Voltage	Truth	Table
1 4010 01	Control	· · · · · · · · · · · · · · · · · · ·		1 4010

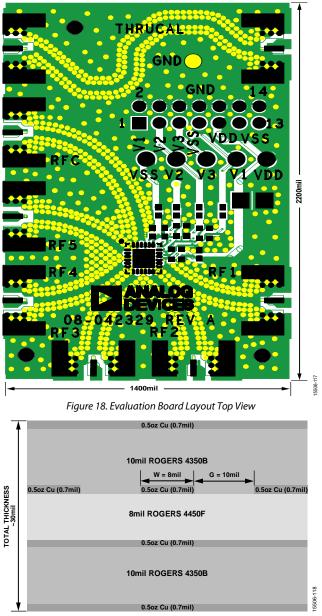
V ₃	V ₂	V 1	Mode	
Low	Low	Low	All Off	
Low	Low	High	RF1 on	
Low	High	Low	RF2 on	
Low	High	High	RF3 on	
High	Low	Low	RF4 on	
High	Low	High	RF5 on	
High	High	Low	All off	
High	High	High	All off	

The ideal power-up sequence is as follows:

- 1. Power up GND.
- 2. Power up VDD and VSS. The relative order is not important.
- 3. Power up the digital control inputs. The relative order of the logic control inputs is not important. However, powering the digital control inputs before the VDD supply can inadvertently forward bias and damage the internal ESD protection structures.
- 4. Apply an RF input signal.

APPLICATIONS INFORMATION EVALUATION BOARD

Figure 18 and Figure 19 show the top and cross sectional views of the evaluation board, which uses 4-layer construction with a copper thickness of 0.5 oz (0.7 mil) and dielectric materials between each copper layer.

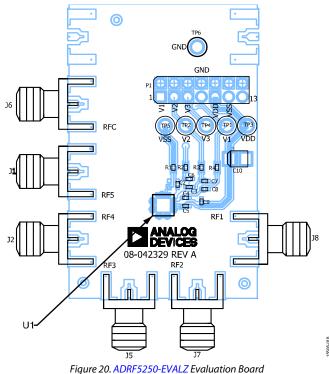




All RF traces are routed on Layer 2; the V1, V3, and VSS dc traces are routed on Layer 3; the V2 and VDD dc traces are routed on the top layer; and the other remaining layers are grounded planes that provide a solid ground for RF transmission lines. The top and bottom dielectric material are Rogers 4350B, offering low loss performance. The middle dielectric material is Rogers 4450F and is used to achieve an overall board thickness of 30 mil. The RF transmission lines were designed using a

coplanar waveguide (CPWG) model with a width of 8 mil and ground spacing of 10 mil for a characteristic impedance of 50 Ω . For optimal RF and thermal grounding, as many plated through vias as possible are arranged around the transmission lines and under the exposed pad of the package.

Figure 20 shows the actual ADRF5250 evaluation board with component placement. Two power supply ports are connected to the VDD and VSS test points, TP3 and TP5, and the ground reference is connected to the GND test point, TP6. On the digital control and VDD supply traces, bypass capacitors are used.



Three control ports are connected to the V1, V2, and V3 test points, TP1, TP2, and TP4, respectively. On each control trace, a resistor position is available to improve the isolation between the RF and control signals. The RF ports are connected to the RFC, RF1, RF2, RF3, RF4, and RF5 connectors (J6, J8, J7, J5, J2, and J1), which are end launch jack SMA RF connectors. A through transmission line that connects unpopulated RF connectors (J3 and J4) is also available to measure the loss of the PCB. Figure 22 and Table 6 show the evaluation board schematic and bill of materials, respectively.

The evaluation board shown in Figure 20 is available for order from the Analog Devices, Inc., website at www.analog.com.

Data Sheet

60 SECONDS TO 150 SECONDS 260°C -5°C/+0°C 217°C 217°C 217°C 480 SECONDS TO 180 SECONDS TO 480 SECONDS TO 480 SECONDS

Figure 21. Pb-Free Reflow Solder Profile

Table 6. Bill of Materials for the ADRF5250-EVALZEvaluation BoardItemDescriptionJ1, J2, J5 to J8RF SMA connectorsTP1 to TP6DC bias test pinsC2 to C5100 pF capacitors, 0402 package

material

0.01 µF capacitor, 0402 package

10 µF capacitor, tantalum package

Evaluation PCB, Rogers 4350B circuit board

ADRF5250

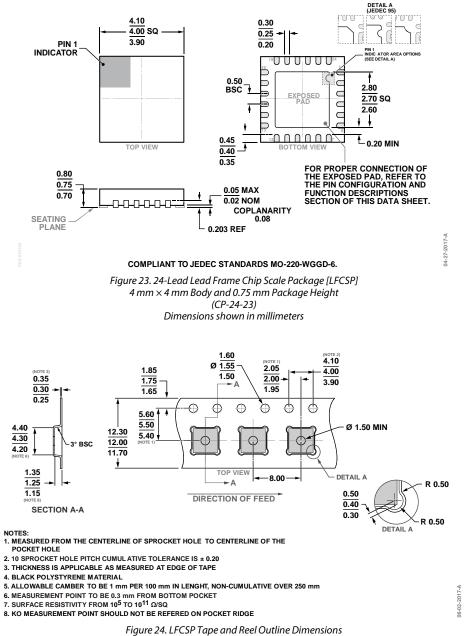
J6 O RFC	$\begin{array}{c c} R1 & VSS \\ 0\Omega & \\ \hline \\ R2 & V3 \\ \hline \\ GND \\ \hline \\ T \\ 100pF \\ GND \\ \hline \\ T \\ 00pF \\ GND \\ \hline \\ \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $
	$\begin{array}{c} & & & & & & \\ \hline & & & & & \\ \hline & & & & \\ GND \end{array} \begin{array}{c} & & & & \\ \hline \\ \hline$
$\begin{array}{c c} & & & \\ & & \\ & & \\ & & \\ & & \\ & & \\$	$\begin{array}{c} R4 & V1 \\ \hline C4 & & C8 & 0\Omega \\ \hline GND & & 100pF & GND & & 0.01\mu F \end{array} $
J1 0 RF5 U1 V1 16 3 GND VDD 15 J2 0 RF4 5 RF4 RF1 6 GND GND GND GND 14 4 GND GND GND GND GND 14	$\begin{array}{c} & VDD \\ C5 \\ GND \\ \hline 100pF \\ GND \\ \hline \end{array} \begin{array}{c} C5 \\ GND \\ \hline \end{array} \begin{array}{c} C9 \\ 0.1 \mu F \\ O \\ \hline \end{array} \begin{array}{c} C9 \\ GND \\ \hline \end{array} \begin{array}{c} +1 \\ C10 \\ 10 \mu F \\ \hline \end{array} \begin{array}{c} C10 \\ 10 \mu F \\ \hline \end{array} \begin{array}{c} RF1 \\ O \\ J8 \end{array}$
GND CND	(⊙) TP6 ↓ GND
GND ↓ RF3 RF2 J5 J7 Figure 22. ADRF5250-EVALZ Evalu	ation Board Schematic

C6 to C9

08-042239

C10

OUTLINE DIMENSIONS



Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
ADRF5250BCPZ	-40°C to +105°C	24-Lead Lead Frame Chip Scale Package [LFCSP]	CP-24-23
ADRF5250BCPZ-R7	-40°C to +105°C	24-Lead Lead Frame Chip Scale Package [LFCSP], 7" Tape and Reel	CP-24-23
ADRF5250BCPZRL	-40°C to +105°C	24-Lead Lead Frame Chip Scale Package [LFCSP], 13" Tape and Reel	CP-24-23
ADRF5250-EVALZ		Evaluation Board	

 1 Z = RoHS Compliant Part.

NOTES



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